

FEATURES:

- Typical $t_{sk(o)}$ (Output Skew) < 250ps
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- $V_{CC} = 3.3V \pm 0.3V$, Normal Range
- $V_{CC} = 2.7V$ to $3.6V$, Extended Range
- CMOS power levels (0.4μ W typ. static)
- All inputs, outputs, and I/O are 5V tolerant
- Supports hot insertion
- Available in TSSOP package

DRIVE FEATURES:

- High Output Drivers: $\pm 24mA$
- Reduced system switching noise

APPLICATIONS:

- 5V and 3.3V mixed voltage systems
- Data communication and telecommunication systems

DESCRIPTION

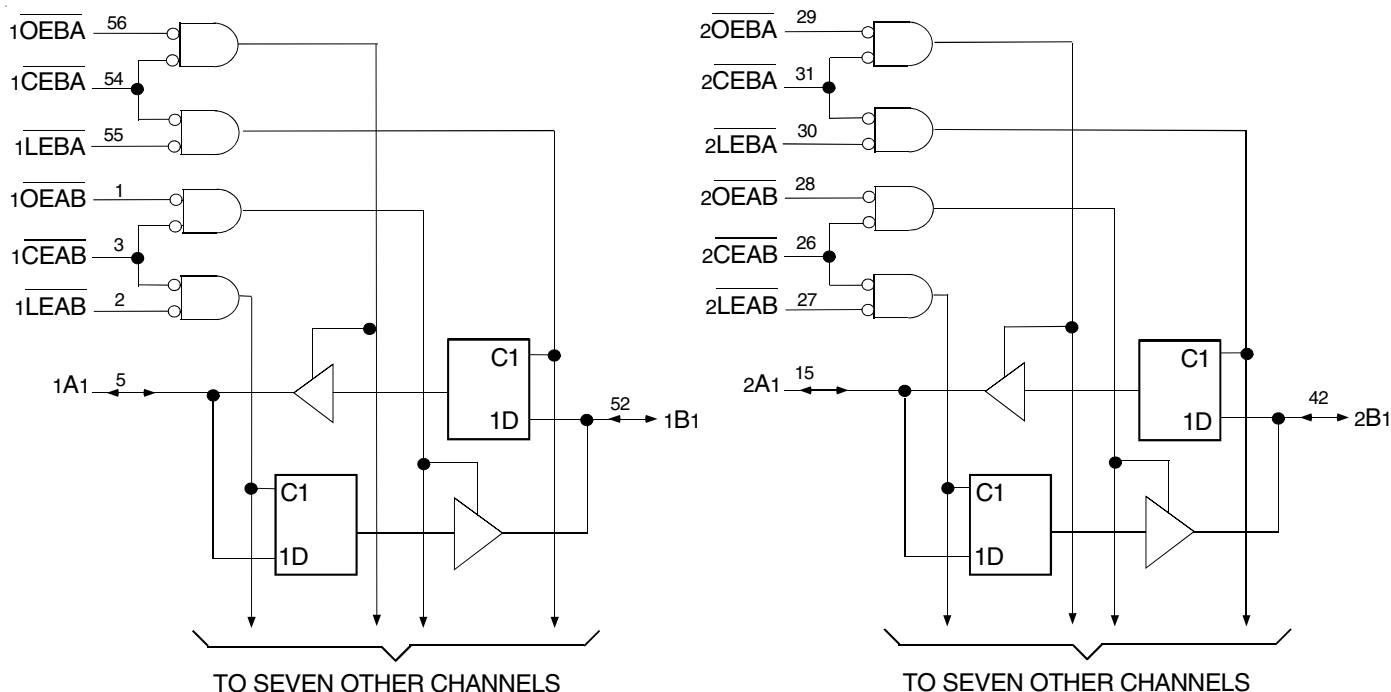
The LVCH16543A 16-bit registered transceiver is built using advanced dual metal CMOS technology. The LVCH16543A can be used as two 8-bit transceivers or one 16-bit transceiver. Separate latch-enable (\overline{LEAB} or \overline{LEBA}) and output-enable (\overline{OEAB} or \overline{OEBA}) inputs are provided for each register to permit independent control in either direction of data flow. The A-to-B enable (\overline{CEAB}) input must be low in order to enter data from the A port or to output data from the B port. \overline{LEAB} controls the latch function. When \overline{LEAB} is low, the A to B latches are transparent. A subsequent low-to-high transition of \overline{LEAB} puts the A latches in the storage mode. \overline{OEAB} performs output enable function on the B port. Data flow from the B port to the A port is similar but requires using \overline{CEBA} , \overline{LEBA} , and \overline{OEBA} inputs. Flow-through organization of signal pins simplifies layout. All inputs are designed with hysteresis for improved noise margin.

All pins of this 16-bit registered transceiver can be driven from either 3.3V or 5V devices. This feature allows the use of this device as a translator in a mixed 3.3V/5V supply system.

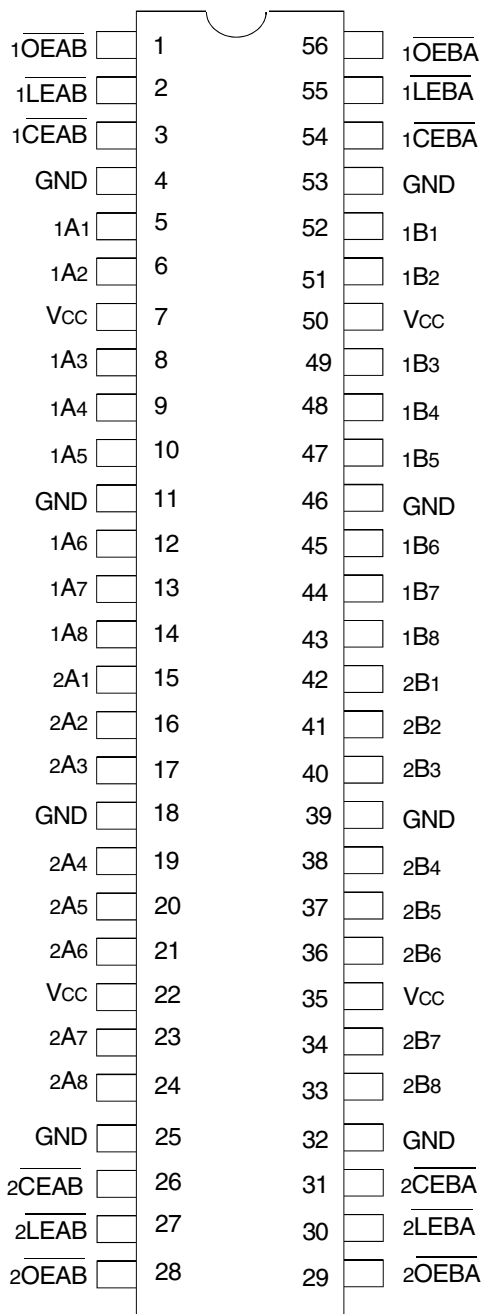
The LVCH16543A has been designed with a $\pm 24mA$ output driver. This driver is capable of driving a moderate to heavy load while maintaining speed performance.

The LVCH16543A has "bus-hold" which retains the inputs' last state whenever the input goes to a high impedance. This prevents floating inputs and eliminates the need for pull-up/down resistors.

FUNCTIONAL BLOCK DIAGRAM



PIN CONFIGURATION



TSSOP
TOP VIEW

CAPACITANCE (TA = +25°C, F = 1.0MHz)

Symbol	Parameter ⁽¹⁾	Conditions	Typ.	Max.	Unit
C _{IN}	Input Capacitance	V _{IN} = 0V	4.5	6	pF
C _{OUT}	Output Capacitance	V _{OUT} = 0V	6.5	8	pF
C _{I/O}	I/O Port Capacitance	V _{IN} = 0V	6.5	8	pF

NOTE:

1. As applicable to the device type.

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max	Unit
V _{TERM}	Terminal Voltage with Respect to GND	-0.5 to +6.5	V
T _{STG}	Storage Temperature	-65 to +150	°C
I _{OUT}	DC Output Current	-50 to +50	mA
I _{IK} I _{OK}	Continuous Clamp Current, V _I < 0 or V _O < 0	-50	mA
I _{CC} I _{SS}	Continuous Current through each V _{CC} or GND	±100	mA

NOTE:

1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

PIN DESCRIPTION

Pin Names	Description
x \overline{OEAB}	A-to-B Output Enable Input (Active LOW)
x \overline{OEBA}	B-to-A Output Enable Input (Active LOW)
x \overline{CEAB}	A-to-B Enable Input (Active LOW)
x \overline{CEBA}	B-to-A Enable Input (Active LOW)
x \overline{LEAB}	A-to-B Latch Enable Input (Active LOW)
x \overline{LEBA}	B-to-A Latch Enable Input (Active LOW)
xAx	A-to-B Data Inputs or B-to-A 3-State Outputs ⁽¹⁾
xBx	B-to-A Data Inputs or A-to-B 3-State Outputs ⁽¹⁾

NOTE:

1. These pins have "Bus-Hold". All other pins are standard inputs, outputs, or I/Os.

FUNCTION TABLE (EACH 8-BIT SECTION)^(1,2)

Inputs			Latch Status	Output Buffers
x \overline{CEAB}	x \overline{LEAB}	x \overline{OEAB}	xAx to xBx	xBx
H	X	X	Storing	High Z
X	X	H	Storing	High Z
L	L	L	Transparent	Current A Inputs
L	H	L	Storing	Previous ⁽³⁾ A Inputs
L	L	H	Transparent	High Z
L	H	H	Storing	High Z
X	H	X	Storing	Not Recommended

NOTES:

- H = HIGH Voltage Level
L = LOW Voltage Level
X = Don't Care
Z = High-Impedance
- A-to-B data flow is shown. B-to-A data flow is similar but uses \overline{xCEBA} , \overline{xLEBA} , and \overline{xOEBA} .
- Before \overline{xLEAB} LOW-to-HIGH transition.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: TA = -40°C to +85°C

Symbol	Parameter	Test Conditions		Min.	Typ. ⁽¹⁾	Max.	Unit
V _{IH}	Input HIGH Voltage Level	V _{CC} = 2.3V to 2.7V		1.7	—	—	V
		V _{CC} = 2.7V to 3.6V		2	—	—	
V _{IL}	Input LOW Voltage Level	V _{CC} = 2.3V to 2.7V		—	—	0.7	V
		V _{CC} = 2.7V to 3.6V		—	—	0.8	
I _{IH} I _{IL}	Input Leakage Current	V _{CC} = 3.6V	V _I = 0 to 5.5V	—	—	±5	μA
I _{OZH} I _{OZL}	High Impedance Output Current (3-State Output pins)	V _{CC} = 3.6V	V _O = 0 to 5.5V	—	—	±10	μA
I _{OFF}	Input/Output Power Off Leakage	V _{CC} = 0V, V _{IN} or V _O ≤ 5.5V		—	—	±50	μA
V _{IK}	Clamp Diode Voltage	V _{CC} = 2.3V, I _{IN} = −18mA		—	−0.7	−1.2	V
V _H	Input Hysteresis	V _{CC} = 3.3V		—	100	—	mV
I _{CC1} I _{CC2} I _{CC3}	Quiescent Power Supply Current	V _{CC} = 3.6V	V _{IN} = GND or V _{CC}	—	—	10	μA
			3.6 ≤ V _{IN} ≤ 5.5V ⁽²⁾	—	—	10	
ΔI _{CC}	Quiescent Power Supply Current Variation	One input at V _{CC} - 0.6V, other inputs at V _{CC} or GND		—	—	500	μA

NOTES:

- Typical values are at VCC = 3.3V, +25°C ambient.
- This applies in the disabled state only.

BUS-HOLD CHARACTERISTICS

Symbol	Parameter ⁽¹⁾	Test Conditions		Min.	Typ. ⁽²⁾	Max.	Unit
IBHH IBHL	Bus-Hold Input Sustain Current	VCC = 3V	VI = 2V	-75	—	—	μA
			VI = 0.8V	75	—	—	
IBHH IBHL	Bus-Hold Input Sustain Current	VCC = 2.3V	VI = 1.7V	—	—	—	μA
			VI = 0.7V	—	—	—	
IBHHO IBHLO	Bus-Hold Input Overdrive Current	VCC = 3.6V	VI = 0 to 3.6V	—	—	±500	μA

NOTES:

- Pins with Bus-Hold are identified in the pin description.
- Typical values are at VCC = 3.3V, +25°C ambient.

OUTPUT DRIVE CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Max.	Unit
VOH	Output HIGH Voltage	VCC = 2.3V to 3.6V	IOH = -0.1mA	VCC - 0.2	—	V
		VCC = 2.3V	IOH = -6mA	2	—	
		VCC = 2.3V	IOH = -12mA	1.7	—	
		VCC = 2.7V		2.2	—	
		VCC = 3V		2.4	—	
		VCC = 3V	IOH = -24mA	2	—	
VOL	Output LOW Voltage	VCC = 2.3V to 3.6V	IOL = 0.1mA	—	0.2	V
		VCC = 2.3V	IOL = 6mA	—	0.4	
			IOL = 12mA	—	0.7	
		VCC = 2.7V	IOL = 12mA	—	0.4	
		VCC = 3V	IOL = 24mA	—	0.55	

NOTE:

1. VIH and VIL must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate VCC range. TA = -40°C to +85°C.

OPERATING CHARACTERISTICS, VCC = 3.3V ± 0.3V, TA = 25°C

Symbol	Parameter	Test Conditions	Typical	Unit
CPD	Power Dissipation Capacitance per Transceiver Outputs enabled	CL = 0pF, f = 10Mhz	44	pF
CPD	Power Dissipation Capacitance per Transceiver Outputs disabled		4	

SWITCHING CHARACTERISTICS⁽¹⁾

Symbol	Parameter	VCC = 2.7V		VCC = 3.3V ± 0.3V		Unit
		Min.	Max.	Min.	Max.	
tPLH tPHL	Propagation Delay, Transparent Mode xAx to xBx or xBx to xAx	—	6.1	1.2	5.4	ns
tPLH tPHL	Propagation Delay xLEBA to xAx, xLEAB to xBx	—	7.4	1.5	6.1	ns
tPZH tPZL	Output Enable Time xCEBA or xCEAB to xAx or xBx	—	7.9	1.2	6.6	ns
tPZH tPZL	Output Enable Time xOEBA or xOEAB to xAx or xBx	—	7.6	1	6.3	ns
tPHZ tPLZ	Output Disable Time xCEBA or xCEAB to xAx or xBx	—	7.1	1.5	6.6	ns
tPHZ tPLZ	Output Disable Time xOEBA or xOEAB to xAx or xBx	—	6.9	1.5	6.3	ns
tsu	Set-up Time, data before CE↑	1.1	—	1.1	—	ns
tsu	Set-up Time, data before LE↑, CE LOW	1.1	—	1.1	—	ns
th	Hold Time, data after CE↑	1.9	—	1.9	—	ns
th	Hold Time, data after LE↑, CE LOW	1.9	—	1.9	—	ns
tw	Pulse Duration, xLEBA or xLEAB, xCEBA or xCEAB LOW	3.3	—	3.3	—	ns
tsk(o)	Output Skew ⁽²⁾	—	—	—	500	ps

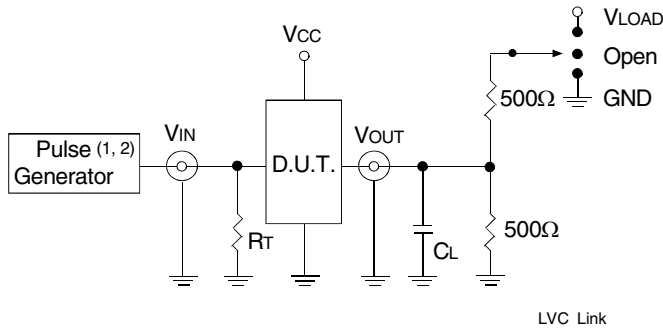
NOTES:

1. See TEST CIRCUITS AND WAVEFORMS. TA = -40°C to +85°C.
2. Skew between any two outputs of the same package and switching in the same direction.

TEST CIRCUITS AND WAVEFORMS

TEST CONDITIONS

Symbol	V _{CC} ⁽¹⁾ =3.3V±0.3V	V _{CC} ⁽¹⁾ =2.7V	V _{CC} ⁽²⁾ =2.5V±0.2V	Unit
V _{LOAD}	6	6	2 x V _{CC}	V
V _{IH}	2.7	2.7	V _{CC}	V
V _T	1.5	1.5	V _{CC} / 2	V
V _{LZ}	300	300	150	mV
V _{HZ}	300	300	150	mV
C _L	50	50	30	pF



Test Circuit for All Outputs

DEFINITIONS:

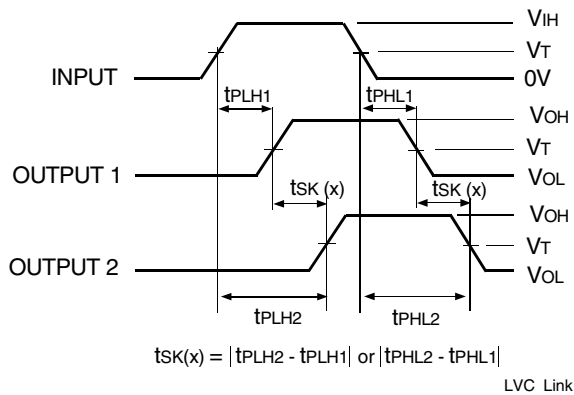
C_L = Load capacitance: includes jig and probe capacitance.
R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator.

NOTES:

1. Pulse Generator for All Pulses: Rate ≤ 10MHz; t_r ≤ 2.5ns; t_r ≤ 2.5ns.
2. Pulse Generator for All Pulses: Rate ≤ 10MHz; t_r ≤ 2ns; t_r ≤ 2ns.

SWITCH POSITION

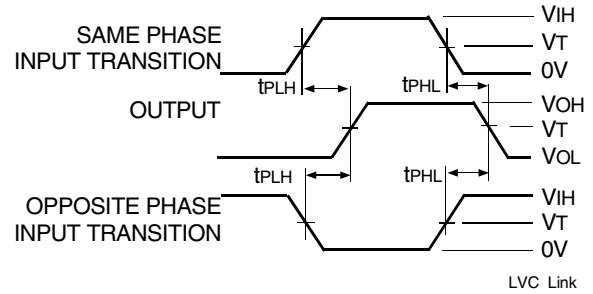
Test	Switch
Open Drain Disable Low Enable Low	V _{LOAD}
Disable High Enable High	GND
All Other Tests	Open



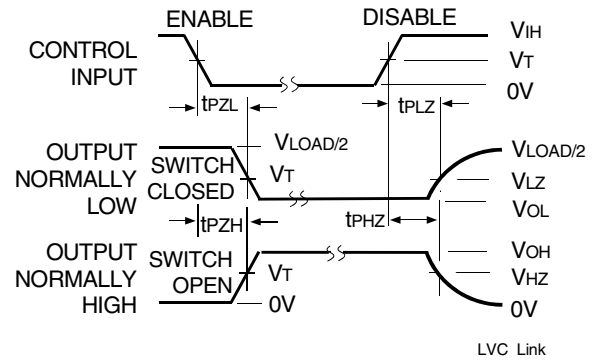
Output Skew - t_{sk}(x)

NOTES:

1. For t_{sk}(o) OUTPUT1 and OUTPUT2 are any two outputs.
2. For t_{sk}(b) OUTPUT1 and OUTPUT2 are in the same bank.



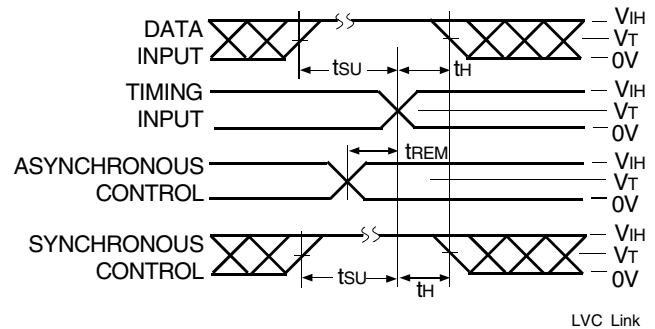
Propagation Delay



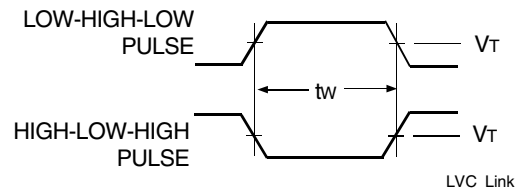
Enable and Disable Times

NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

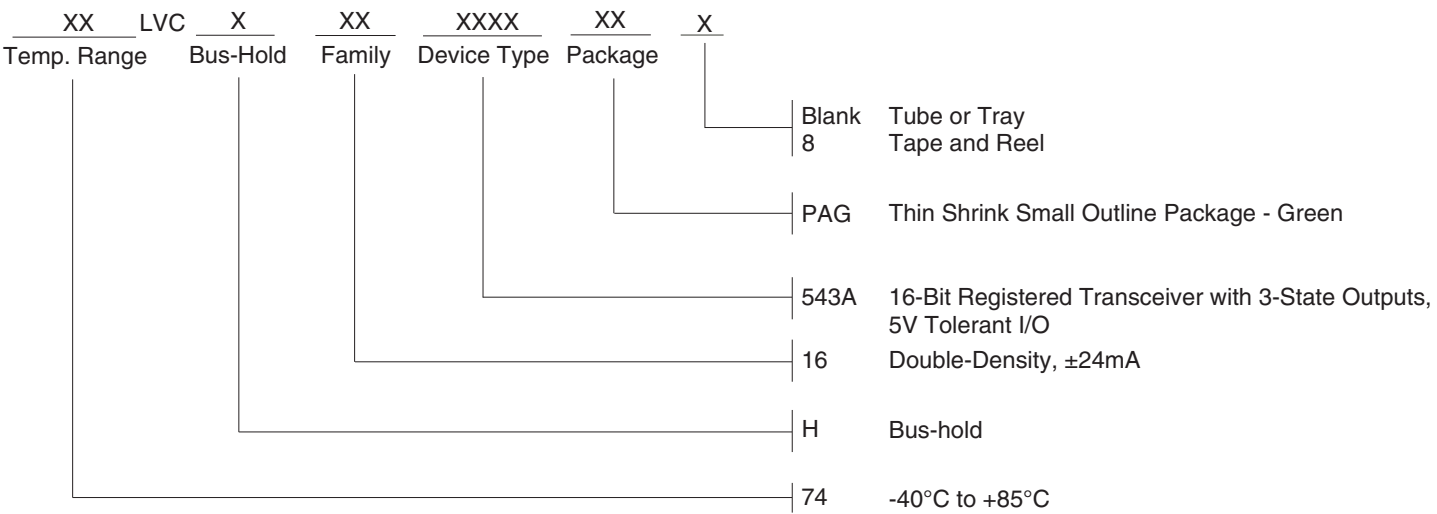


Set-up, Hold, and Release Times



Pulse Width

ORDERING INFORMATION



DATASHEET DOCUMENT HISTORY

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